

UNDER DEVELOPMENT  
PRELIMINARY

TOSHIBA PHOTOCOUPLER    PHOTORELAY

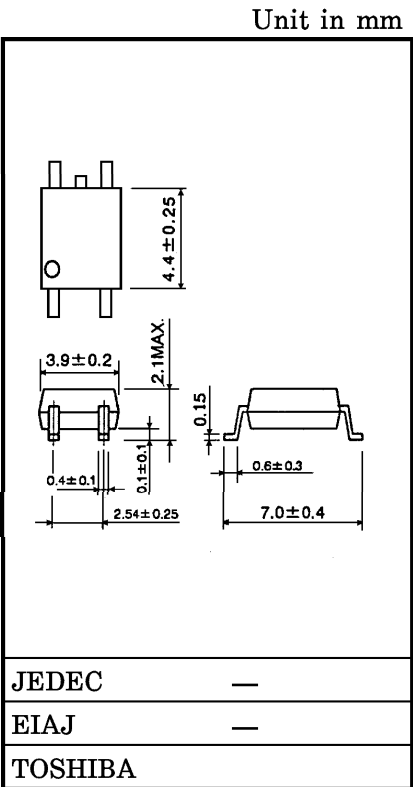
TLP3113

MEASUREMENT INSUTRUMENTS

- LOGIC IC TESTERS / MEMORY TESTERS
- BOARD TESTERS / SCANNERS

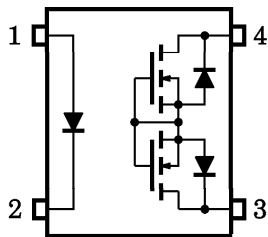
The Toshiba TLP3113 Mini-flat photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP3113 consists of a GaAs infrared-emitting diode optically coupled to a photo-MOSFET and housed in a 4-pin package. Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measuring instruments.

- SOP (2.54SOP4) : 2.1 mm high, 2.54-mm pitch
- 1 Form A
- Peak OFF-State Voltage : 40 V (min)
- Trigger LED Current : 4 mA (max)
- ON-State Current : 100 mA (max)
- ON-State Resistance : 35 Ω (max)
- Output Capacitance : 0.9 pF (max)
- Isolation Voltage : 1500 Vrms (min)



Weight : 0.1 g

PIN CONFIGURATION (TOP VIEW)



- 1 : ANODE
- 2 : CATHODE
- 3 : DRAIN
- 4 : DRAIN

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## MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC                                      |  | SYMBOL     | RATING  | UNIT |
|---|--|------------|---------|------|
| LED   | Forward Current                            | $I_F$      | 50      | mA   |
|   | Reverse Voltage                            | $V_R$      | 6       | V    |
|   | Junction Temperature                       | $T_j$      | 125     | °C   |
| DETECTOR  | OFF-State Output Voltage                   | $V_{OFF}$  | 40      | V    |
|   | ON-State Current                           | $I_{ON}$   | 100     | mA   |
|   | Peak ON-State Current (t = 100 ms, 1 shot) | $I_{peak}$ | 0.3     | A    |
|   | Junction Temperature                       | $T_j$      | 125     | °C   |
| Storage Temperature                                 |  | $T_{stg}$  | -55~125 | °C   |
| Operating Temperature                               |  | $T_{opr}$  | -20~85  | °C   |
| Lead Soldering Temperature (10 s)                   |  | $T_{sol}$  | 260     | °C   |
| Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1) |  | $BV_S$     | 1500    | Vrms |

(Note 1) : Device considered a two-pin device : Pin 1 and 2 shorted together, and pins 3 and 4 shorted together.

## RECOMMENDED OPERATING CONDITIONS

| CHARACTERISTIC        | SYMBOL    | MIN | TYP. | MAX | UNIT |
|-----------------------|-----------|-----|------|-----|------|
| Supply Voltage        | $V_{OFF}$ | —   | —    | 32  | V    |
| Forward Current       | $I_F$     | 10  | —    | 30  | mA   |
| ON-State Current      | $I_{ON}$  | —   | —    | 100 | mA   |
| Operating Temperature | $T_{opr}$ | 25  | —    | 60  | °C   |

## INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC |                    | SYMBOL    | TEST CONDITION                                   | MIN | TYP. | MAX  | UNIT          |
|----------------|--------------------|-----------|--|-----|------|------|---------------|
| LED            | Forward Voltage    | $V_F$     | $I_F = 20 \text{ mA}$                            | 1.0 | 1.2  | 1.4  | V             |
|                | Reverse Voltage    | $I_R$     | $V_R = 6 \text{ V}$                              | —   | —    | 10   | $\mu\text{A}$ |
|                | Capacitance        | $C_T$     | $V = 0, f = 1 \text{ MHz}$                       | —   | 15   | —    | pF            |
| DETECTOR       | OFF-State Current  | $I_{OFF}$ | $V_{OFF} = 30 \text{ V}, T_a = 50^\circ\text{C}$ | —   | —    | 1000 | pA            |
|                | Output Capacitance | $C_{OFF}$ | $V = 0, f = 100 \text{ MHz}$                     | —   | 0.6  | 0.9  | pF            |

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC      | SYMBOL | TEST CONDITION          | MIN | TYP. | MAX | UNIT |
|---------------------|--------|-------------------------|-----|------|-----|------|
| Trigger LED Current | IFT    | ION = 100 mA            | —   | —    | 4   | mA   |
| ON-State Resistance | RON    | ION = 100 mA, IF = 5 mA | —   | 25   | 35  | Ω    |

ISOLATION CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC              | SYMBOL | TEST CONDITION         | MIN                  | TYP.             | MAX | UNIT |
|-----------------------------|--------|------------------------|----------------------|------------------|-----|------|
| Capacitance Input to Output | CS     | VS = 0 V, f = 1 MHz    | —                    | 0.8              | —   | pF   |
| Isolation Resistance        | RS     | VS = 500 V, R.H. ≤ 60% | 5 × 10 <sup>10</sup> | 10 <sup>14</sup> | —   | Ω    |
| Isolation Voltage           | BVS    | AC, 1 min              | 1500                 | —                | —   | Vrms |
|                             |        | AC, 1 s (in oil)       | —                    | 3000             | —   |      |
|                             |        | DC, 1 min (in oil)     | —                    | 3000             | —   | Vdc  |

SWITCHING CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION         | MIN | TYP. | MAX | UNIT |
|----------------|--------|------------------------|-----|------|-----|------|
| Turn-on Time   | tON    | RL = 200 Ω (Note 2)    | —   | —    | 1   | ms   |
| Turn-off Time  | tOFF   | VDD = 20 V, IF = 10 mA | —   | —    | 1   |      |

(Note 2) : SWITCHING TIME TEST CIRCUIT



PRELIMINARY

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